Abstract Submitted
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**Effects of finite layer thickness on the differential capacitance of electron bilayers**[1] J.J. DURRANT, C.B. HANNA, Boise State University — We have calculated the effects of the finite thickness of electron or hole layers in double-quantum-well systems on the complete set of differential capacitances that can be measured in double-layer electron systems, with or without separately contactable layers. We present results for the regime of negligible interlayer tunneling, zero applied magnetic field, and low layer densities, when the compressibility of one or both layers is negative.

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